Reply Date: November 12, 2009

AMENDMENTS TO THE CLAIMS

This list of claims will replace all prior claims lists in this application. List of Claims:

(Currently amended) A method of sealing two substrates in a microstructure,—comprising the following steps:

depositing a first rim onto a surface of a first substrate, said first rim comprising an upper rim comprising a layer of sealing material that interdiffuses spontaneously with a material of a second substrate and a lower rim comprising an adhesion material that adheres said first substrate to said sealing material:

depositing a second rim onto a surface of at least one protuberance formed on said second substrate facing said first rim, said second rim comprising a layer of said sealing material:

wherein said second rim overlies a surface of at least one protuberance on said second substrate, the at least one protuberance having a plurality of hollows or a meshed structure and adapted to channel the diffusion of said sealing material;

bringing said upper rim and said second rim into contact; and

heating said sealing material to interdiffuse said sealing material and said material of said second substrate, the at least one protuberance channeling the diffusion of said sealing material.

- (Previously presented) The sealing method according to claim 1, wherein said sealing material and a material of said first substrate comprise materials that diffuse into each other and wherein said lower rim forms a barrier to diffusion.
- 3. (Previously presented) The sealing method according to claim 1, wherein said sealing material and a material of said first substrate comprise materials that diffuse into each other and wherein said first rim further comprises a layer forming a barrier to diffusion between said lower rim and said upper rim.
- 4. (Previously presented) The sealing method according to claim 1, wherein said first substrate comprises silicon.
 - 5. (Previously presented) The sealing method according to claim 1, wherein

Reply Date: November 12, 2009

said second substrate comprises silicon.

- 6. (Previously presented) The sealing method according to claim 1, wherein said sealing material comprises gold.
- 7. (Currently amended) The sealing method according to claim 2, wherein said barrier layer-comprises tungsten.
- 8. (Withdrawn) A sealing region between two substrates of a microstructure, wherein said sealing region is made by the method according to claim 1.
- (Withdrawn) A sealing region between two substrates of a microstructure, comprising:
- a lower rim on a first substrate, the lower rim comprising an adhesion material that adheres said first substrate to a sealing material that interdiffuses spontaneously with a material of a second substrate;
 - a layer of said sealing material on said lower rim; and
- a protuberance on said second substrate, said protuberance containing a quantity of sealing material and contacting said layer of sealing material.
- (Withdrawn) The sealing region according to claim 9, wherein said sealing material and a material of said first substrate diffuse into each other and wherein said lower rim forms a parrier to diffusion
- 11. (Withdrawn) The sealing region according to claim 9, wherein said sealing material and a material of said first substrate diffuse into each other and wherein said sealing region further comprises a layer forming a barrier to diffusion between said lower rim and said layer of sealing material.
- 12. (Withdrawn) The sealing region according to claim 8, wherein said surface of said protuberance comprising a plurality of hollows.
- (Withdrawn) The sealing region according to claim 8, wherein said surface of said protuberance comprises a meshed structure.

Reply Date: November 12, 2009

 (Withdrawn) The sealing region according to claim 8, wherein said first substrate comprises silicon.

- 15. (Withdrawn) The sealing region according to claim 8, wherein said second substrate comprises silicon.
- (Withdrawn) The sealing region according to claim 8, wherein said sealing material comprises gold.
- (Withdrawn) The sealing region according to claim 10, wherein said barrier layer comprises tungsten.
- 18. (Withdrawn) A microstructure comprising a sealing region according to claim 8.
- (Previously presented) The sealing method according to claim 3, wherein said barrier comprises tungsten.
- (Withdrawn) The sealing region according to claim 9, wherein said surface
 of said protuberance comprises a plurality of hollows.
- (Withdrawn) The sealing region according to claim 9, wherein said surface of said protuberance comprises a meshed structure.
- 22. (Withdrawn) The sealing region according to claim 9, wherein said first substrate comprises silicon.
- 23. (Withdrawn) The sealing region according to claim 9, wherein said second substrate comprises silicon.
- 24. (Withdrawn) The sealing region according to claim 9, wherein said sealing material comprises gold.
- (Withdrawn) The sealing region according to claim 11, wherein said barrier comprises tungsten.

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Reply Date: November 12, 2009

26.- 27 (Cancelled)

- 28. (New) The sealing method according to claim 1 further comprising etching said second substrate using said second rim as an etch mask to form said at least one protuberance.
- 29. (New) The sealing method according to claim 1, wherein said upper rim is configured to form a reservoir for said sealing material and to facilitate interdiffusing said sealing material and said material of said second substrate.
- 30. (New) The sealing method according to claim 1, wherein said plurality of hollows or meshed structure is configured to retain a portion of molten sealing material.